MIL-9-19500/331A(EL) 8 February 1971

SUPERSEDING MIL-S-19500/331 (EL) 5 May 1965

MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, TRANSISTOR, PNP, GERMANIUM, POWER TYPES 2N1553A THROUGH 2N1556A

1. SCOPE

- 1.1 Scope. This specification covers the detail requirements for germanium, PNP, power transistors for particular use in power-switching, electronic-circuit applications. (See 3.4 and 6.2) herein.)
 - 1.2 Outline and dimensions. See Fig. 1 herein. (TO-3)
 - 1.3 Maximum ratings.-(At T_C =+25°C, unless otherwise specified):

	$P_{T}^{1/2}$	T _J	v _{сво}	VCEO	V _{EBO}	IB	I _C	T _A (range)
	W	° C	Vdc	Vdc	Vdc	Adc	Adc	ို
2N1553A	90	100	-50	-20	-20	-5	-15	-65 to +100
2N1554A	90	100	-60	-30	-30	-5	-15	-65 to +100
2N1555A	90	100	-80	-40	-40	-5	-15	-65 to +100
2N1556A	90	100	-100	-70	-50	-5	-15	-65 to +100

- 1/ Between $T_C > 25^{\circ}$ C and up to $T_C = +100^{\circ}$ C, derate linearly at 1.20 W/°C.
 - 1.4 Particular electrical characteristics. (At T_C=+25°C, unless otherwise specified):

			h _{FE}		VBE (sat)	VCE	(sat)	hf	е		Swite	hing	
	-								f=10	OkHz	t _d	tr	ts	tf
	IC=-	5Adc -2Vdc	IC=-	10Adc -2Vdc	I _C =-	10Adc	I _C =	-10Adc -1Adc	I _C =-	5Adc -2Vdc		Table 2 he	I ar erein)	
	Min	Max	Min	Max	Min			Max	Min	Max	Max	Max	Max	Max
A11					Vdc	Vdc	Vdc	Vdc			usec	usec	usec	usec
Types	30	90	30	60		-1.0		-0.7	1.0	4.0	2	10	5	30

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APPLICABLE DOCUMENTS 2.

2.1 The following documents, of the issue in effect on date of invitation for bids or request for proposal, form a part of this specification to the extent specified herein:

SPECIFICATIONS MILITARY

MIL-S-19500

Semiconductor Devices, General Specification For

STANDARDS MILITARY

MIL-STD-202 Test Methods for Electronic and Electrical Component Parts

MTI.-STD-750

Test Methods for Semiconductor Devices

(Copies of specifications, standards, drawings, and publications required by contractors in connection with specific procurement functions should be obtained from the procuring activity or as directed by the contracting officer. Both the title and number or symbol should be stipulated when requesting copies.)

REQUIREMENTS 3.

- Requirements.-Requirements for the transistor shall be in accordance with Specification MIL-S-19500 and as otherwise specified herein.
- Abbreviations and symbols. The abbreviations and symbols used herein are defined in Specification MIL-S-19500.
- Design and construction. The transistor shall be of the design, construction, and physical dimensions specified in Figure
- 3.3.1 Terminal arrangement.-The terminal arrangement on the transistor shall be as indicated in Figure 1.
- 3.3.2 Operating position. The transistor shall be capable of proper operation in any position.
- Performance characteristics .- The transistor performance characteristics shall be as specified in Tables I, II, and III herein.

- 3.5 Marking.-Except as otherwise specified herein, marking shall be in accordance with specification MIL-S-19500.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 General.-Sampling and inspection shall be in accordance with specification MIL-S-19500, and as specified herein.
- 4.1.1 <u>Inspection lot</u>.-Applicable to the semiconductor device(s) covered herein, the term "inspection lot" shall be as defined in paragraph 4.3.2.1 of specification MIL-S-19500 except that the 6-week-period time limitation stipulated therein shall be considered as not compulsory.
- 4.1.1.1 <u>Preconditioned-unit constituency of inspection lots</u>.-All semiconductor devices covered herein, in each inspection lot presented for Quality Conformance inspection, shall have been subjected to the following preconditioning:
 - (a) Maintained at $T_A = +100^{\circ} \text{C}$ minimum, for 96 ± 8 hours minimum.
- 4.2 Qualification and acceptance inspection.-Qualification and Quality Conformance inspection shall be in accordance with specification MIL-S-19500, Quality Assurance Provisions, and as otherwise specified herein. Groups A, B, and C inspection shall consist of the examinations and tests specified in Tables I, II, and III, respectively, herein. Quality Conformance inspection shall include inspection of Preparation for Delivery (see 5.1 herein).
- 4.2.1 Special Group A criteria for Qualification inspection. For Qualification inspection, only 10 failures will be permitted for all Group A tests combined. Hereto, where the manufacturer deems that the data in paragraph 4.4.2 of specification MIL-S-19500 are invokable, notification shall be made to the Chief, Components and Materials Standardization Branch, Procurement and Production Directorate, Fort Monmouth, New Jersey 07703, Attention: AMSEL-PP-EM-2.
- 4.2.2 Permissible Group B or Group C combined-subgroup testing. At option of the manufacturer, all of the tests on one subgroup in Group B (Table II herein) may be combined with all of the tests in one or more other subgroup(s) of Group B for sequential performance; the same option applies to Group C (Table III herein) constituent subgroup. Under this option, the sample units per applicable LTPD or lambda (λ) for one of the subgroups may be used to form the sample quantity required per LTPD or lambda(λ) for anyone of the other subgroups. Accept-reject criteria normally applicable for each respective subgroup shall be effective. The following administrative requirements shall apply hereto:
 - a. It shall be understood that the above option may be adopted by manufacturer for Qualification testing of product, or for Quality Conformance inspection of any individual lot submitted by manufacturer for lot acceptance.

- b. Prior notification as to adoption of this testing option, and concurrent information as to the predesignated sample quantities to be used shall be made to the Government inspection authority concerned.
- c. Complete record of the combined subgroup testingprogram results shall be maintained and be available to the Government inspection authority.
- 4.2.3 Group B-Group C life test samples. Samples that have been subjected to Group B, 340-hour life test may be continued on test for 1000 hours in order to satisfy Group C life test requirements. These samples shall be predesignated, and shall remain subjected to the Group C, 1000-hour evaluation after they have passed the Group B, 340-hour acceptance criteria. The cumulative total of failures found during 340-hour test and during the subsequent interval up to 1000 hours shall be computed for 1000-hour acceptance. (See 4.2.4 below).
- 4.2.4 <u>Group C testing.</u>-Group C tests shall be performed on a lot every 6 months. (See Table III herein). The contractor shall, throughout the course of a contract or order, permit the Government representative to scrutinize all test data and findings covering manufacturer's test program on Group C characteristics and parameters for the product concerned. Upon determination by the Government inspector (in advance of Group C, 6-month, test results) that Group C parameters are not being adequately met, the Government inspector may require lot-by-lot inspection, normally for a minimum of 3 consecutive lots, to be performed for required Group C tests.
- 4.2.5 <u>Disposition of sample units.</u>-Sample units that have been subjected to Group B, Subgroup 2 and 4 tests shall not be delivered on the contract or order. Sample units that have been subjected to and have passed Group B, Subgroups 1, 3, 5, 6, and 7 tests and all Group C tests (these tests to be considered non-destructive), may be delivered on the contract or order provided that, after Group B and C inspection is terminated, those sample units are subjected to and pass Group A inspection. Defective units from any sample group that may have passed group inspection shall not be delivered on the contract ororder until the defect(s) has been remedied to the satisfaction of the Government.
 - 4.3 Particular examination and test requirements.-
- 4.3.1 "Pulse measurements".-Conditions for "Pulse Measurements" shall be as specified in Section 4 of MIL-STD-750.
- 4.3.2 Hermetic seal test.-The transistors shall be subjected to hermetic seal test(s) in accordance with Method 1071 in MIL-STD-750 except that the following test conditions therein shall apply hereto:

- a. Fine-leak test: per Test Condition G or H; however, a maximum leakage rate of 5×10^{-7} atm cc/sec shall be effective for acceptance.
- b. Gross-leak test: per Test Condition A, C, D, or F.
- 4.3.3 Safe operating are (DC operation) test.-Satisfactory endurance of the transistors throughout Test #1, #2, #3, respectively, (per Table II, Subgroup 5, herein) is directly related to the "safe operating area: for the transistors as determinable from the graphs of Figure 3 herein. (The 3 points tested per Test #1, 2, 3 are locatable on the boundaries of "safe operating area".)
- 4.3.4 Marking resistance to solvents test.-The device samples shall be subjected to test per Method 215 in MIL-STD-202. The following details shall apply:
 - a. All surface areas on the body of the device where marking has been applied shall be brushed.
 - b. All marking shall have remained legible, and there shall be no evidence of mechanical damage to the device, upon examination after test.
- 4.3.5 Maximum current test.-With the base lead electrically connected to the collector terminal, the current specified shall be applied through the emitter lead for the time duration specified. Suitable means should be employed so that the case temperature will not exceed +71°C.
- 4.3.6 Mechanical damage resulting from tests.-Except for intentionally deforming, mutilating, or dismembering mechanical-stress tests to which samples are subjected, there shall be no evidence of mechanical damage to any sample unit as a result of any of the Group A, B, or C tests.

Table I. Group A inspection.

	18016	. Group A z	nopec c.				
Test Method per MIL-STD-750	Examination of test	Conditions	LTPD	Symbol	<u>Lim</u> Min	its Máx	Unit
	Subgroup 1		20				
2071	Visual and mechanical examination			 `		⇔ ••••••••••••••••••••••••••••••••••••	
	Subgroup 2		15				
3001	Collector-base breakdown voltage:	Test Cond D		BV _{CBO}			Vdc
	2N1553A 2N1554A 2N1555A 2N1556A				-50 -60 -80 -100		
3011	Collector- emitter break- down voltage:	Test Cond D IC=-500mAdc		BVCEO			Vdc
	2N1553A 2N1554A 2N1555A 2N1556A				- 20 - 30 - 40 - 70		
3011	Collector- emitter break- down voltage:	Test Cond C I _C =-500mAdc		BVCES			Vďc
		<u>1</u> /					
	2N1553A 2N1554A 2N1555A 2N1556A				- 30 - 45 - 60 - 80		
3036	Collector-base cutoff current:	Test Cond D		Ісво			mAdc
	2N1553A	V _{CB} =- 25Vdc				- 3	
	2N1554A	$V_{CB}^{=-40Vdc}$				- 3	
	2N1555A	V _{CB} =-55Vdc				- 3	
	2N1556A	V _{CB} =-65Vdc				- 3	

Table I. Group A inspection - (Cont'd)

	Table 1. Group	A Inspection	, 00.				
Test Method per MIL-STD-750	Examination or test	Conditions	LTPD	Symbol	<u>Limi</u> Min	ts Max	<u>Unit</u>
MIL OIL /30	Subgroup 2 - (Co	nt'd)					
3041	Collector- emitter cut- off current:	Test Cond A V _{BE} =+1Vdc		ICEX			mAdc.
	2N1553A 2N1554A 2N1555A 2N1556A	V _{CE} =-50Vdc V _{CE} =-60Vdc V _{CE} =-80Vdc V _{CE} =-100Vdc				- 20 - 20 - 20 - 20	
3061	Emitter-base cutoff current:	Test Cond D		IEBO			mAdc
	2N1553A 2N1554A 2N1555A	V _{EB} =-12Vdc V _{EB} =-12Vdc V _{EB} =-12Vdc				-0.5 -0.5	
3076	2N1556A Forward-current transfer ratio	V _{EB} =-12Vdc		h _{FE}	30	-0.5 90	
3076	Forward-current transfer ratio	I _C =-10Adc V _{CE} =-2Vdc		h _{FE}	30	60	
3066	Base-emitter saturation voltage	Test Cond A I _C =-10Adc I _B =-1Adc		V _{BE} (sa	t)	-1.0) Vdc
3071	Collector- emitter saturation voltage	I _C =-10Adc I _B =-1Adc		V _{CE} (sa	t)	-0.7	7 Vdc

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Table I. Group A inspection - (Cont'd)

							
Test Method per MIL-STD-750	Examination or test	Conditions	LTPD	Symbol	Limi Min	ts Max	Unit
	Subgroup 3		10				
3251	Pulse response	Test Cond A except test circuit per Fig. 2 herein					•
		I _C =-10A V _{CC} =-10V I _{B1} =-I _{B2} =360m	n A				
	Rise time			t _r		10	usec
	Delay time			^t d		2	usec
	Storage time			ts		5	usec
	Fall time			^t f	~ -	30	usec
3306	Magnitude of common-emitter small-signal short-circuit forward-current transfer ratio	I _C =-5Adc V _{CE} =-2Vdc f=100kHz		h _{fe}	1.0	4.0	••

<u>1</u>/ See 4.3.1 herein.

Table II. Group B inspection.

Test Method per Examination or test Conditions LTPD Symbol Min Max Subgroup 1 20 2066 Physical dimensions Subgroup 2 15 2031 Soldering heat 1 cycle Temperature cycling except	Unit
Per Examination or test Conditions LTPD Symbol Min Max Subgroup 1 20 2066 Physical dimensions Subgroup 2 15 2031 Soldering heat 1 cycle 1051 Temperature Test Cond B	Unit
Subgroup 1 20 2066 Physical See Fig. 1 dimensions Subgroup 2 15 2031 Soldering heat 1 cycle 1051 Temperature Test Cond B	
dimensions Subgroup 2 2031 Soldering heat 1 cycle 1051 Temperature Test Cond B	
2031 Soldering heat 1 cycle 1051 Temperature Test Cond B	
1051 Temperature Test Cond B	
10)1	
cycling except. T(high) +100° +3C	
1056 Thermal shock Test Cond B (glass strain)	
2036 Terminal strength:	
Tension Test Cond A Weight=10 1bs. t=15 sec each terminal	
Torque Test Cond D1 Torque=6 oz-in t=15 sec each terminal	
1071 Hermetic seal $\underline{3}/$ 5 x 10^{-7}	
1021 Moisture No initial resistance conditioning	
End-Point tests:	
3036 Collector-base Test Cond D ^I CBO cutoff current	mAdc
2N1553A V _{CB} =-25Vdc3	
$2N1554A \qquad V_{CR} = -40Vdc$	
2N1555A V _{CB} =-55Vdc	
2N1556A V _{CB} =-65Vdc3	}

Table II. Group B inspection - (Cont'd)

	10010 111		•				
Test Method per MIL-STD-750	<u>l</u> / Examination or test	<u>2</u> / Conditions	LTPD	Symbol	<u>Lim</u> Min	its Max	Unit
MIL-BID 750	Subgroup 2 - (Co	nt'd)					
3076	Forward current transfer ratio	$I_C = -10Adc$ $V_{CE} = -2Vdc$		h _{FE}	30	60	
	Subgroup 3		15				
2016 :	Shock	Non-operating 1500G 5 blows of 0.5 msec ea. in orienta- tions X1, Y1 Y2, Z1 (tota =20 blows)	•	.·		· · · · ·	.
2056	Vibration, variable frequency	10G					wa 40 KB
2006	Constant accel- eration (cen- trifugal)	5000G Orientations X1, Y1, Y2,					••
	End-Point tests	:					
	Same as for Subgroup 2 above						
	Subgroup 4		15				
1041	Salt atmosphere (corrosion)	<u>4</u> /		~ ~			
	Subgroup 5		15				
3052	Safe operating area (pulsed):	5/ f=200Hz t=250 usec See Fig. 4			an an 4h		
		JUL 1 - 5 - T					

Table	II.	Group	В	inspection	-	(Cont'd)	
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Test Method per	$\frac{1}{2}$	<u>2</u> /			Limits	••
MIL-STD-750	test	Conditions	LTPD	Symbol	Min Max	Unit
	Subgroup 5 - (C	ont'd)				
3052 (Cont'd)	Test #1:	I _C =- 20A				
(cont u)	2N1553A	V _{CE} =- 25V				
	2N1554A	V _{CE} =- 35V				
	2N1555A	V _{CE} =-45V				
	2N1556A	V _{CE} =-45V		•		
	Test #2:					
	·2N1553A	I _C =-1.0A				
		V _{CE} =- 29V				
	2N1554A	I _C =-1.0A				
	0113 5 5 5 4	V _{CE} =-43V		;		
	2N1555A	Ic=-2.2A				
	011 EE 6 A	V _{CE} =-55V I _C =-3.0A		•		
	2N1556A	V _{CE} =-65V				
	Test #3:	$_{\rm T_{\rm C}} \approx +70^{\circ} + \frac{3}{0} {\rm C}$				
		See Fig. 5 t=5 minutes;				
		min., con-	,			
•		tinuous				
	2N1553A	I _C =-1.8A				
		V _{CE} =- 20V				
	2N1554A	I _C =-1.25A				
		V _{CE} =-30V				
	2N1555A	I _C =-1.0A				
		V _{CE} =-37V				
	2N1556A	I _C =-0.75A V _{CE} =-50V				
	End-Point test				·	
	Same as for Gr Subgroup 2	oup B,				

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Table II. Group B inspection - (Cont'd)

Test Method	1/	<u>2</u> /			Limi	1+0	
per MIL-STD-750	Examination or test	Conditions	LTPD	Symbol	Min	Max	Unit
MIL-51D-750	Subgroup 6		10				
1032	High-tempera- ture life (non- operating)	$T_{\text{stg}} = 100^{\circ} + 3^{\circ} \text{ o}$ t = 340 hrs.	;				
	End-Point tests	• •				٠.	- .
3036	Collector- base cutoff current:	Test Cond D		ICBO			mAdc
	2N1553A	V_=- 25Vdc				-4.5	ı
	2N1554A	V _{CB} =-40Vdc		٠		-4.5	
	2N1555A	v_{CB}^{55Vdc}				-4.5	
	2N1556A	$V_{CB}^{=-65Vdc}$			~ ~ ~	-4.5	i
3076	Forward- current trans- fer ratio	I _C =-10Adc V _{CE} =-2Vdc		h _{FE}	23	70	
	Subgroup 7	_	20				
1027	Steady-state operation life	$T_{c}=+80^{\circ}+3^{\circ} C$ $P_{T}=20W$ $V_{CB}=-15^{+10} V_{CB}$ $t=340 \text{ hrs}$.	c	•			
		<u>6</u> /					
	End-Point tests	<u>5</u> :					
	Same as for Subgroup 6 above	ve					

See 3.4 herein.
See 4.2.2 herein.
See 4.3.2 herein.
Electrical rejects from the same lot under evaluation may be used for this test.
See 4.3.3 herein.
See 4.2.3 herein.

Table III. Group C inspection. 1/

· · · · · · · · · · · · · · · · · · ·		2/					
Test Method	Examination or	<u>2</u> /		_	Limi		•• • .
per MIL-STD-750	test	Conditions	LTPD	Symbol	Min	Max	Unit
	Subgroup 1		15				
<u>3</u> /	Marking resis- tance to solvents	<u>4</u> /					
	Subgroup 2		15				0
3151	Thermal resistance	35 de 18 ∵ ·	:	- - 0 _J ८		0.8	°C/W
<u>5</u> /	Maximum current	I _E =-15Adc t=1 hour					
	End-Point tests	:					
3036	Collector- base cutoff current	Test Cond D		ICBO			mAdc
•	2N1553A	V _{CB} =- 25Vdc				-4.5	
	2N1554A	V_p=-40Vdc	•			-4.5	
	2N1555A	V _{CB} =-55Vdc				-4.5	
	2N1556A	V_{CB}^{CB} =-65Vdc				-4.5	5 .
3076	Forward cur- rent transfer ratio	I _C =-10Adc V _{CE} =-2Vdc		${\tt h}_{ m FE}$	23	70	
	Subgroup 3 6/	•	15				
<u>7</u> /	High-tempera- ture opera- tion:	T _C =+90°+3° C					
3036	Collector-base cutoff current:	Test Cond D		ICBO			mAdc
	2N1553A	V _{CB} =-15Vdc				- 20	
	2N1554A	V _{CB} =-22.5Vd	С			- 20	
	2N1555A	V _{CB} =-30Vdc				- 20	
	2N1556A	v _{CB} =-37.5Vd	c			- 20	ı
		GD.					

Table III. Group C inspection. $\frac{1}{-}$ (Cont'd)

	14010 1111			•			
Test Method per MIL-STD-750	Examination or test	<u>2</u> / Conditions	LTPD	Symbol	<u>Lim</u> Min	its Max	Unit
FILE-SID 750		(Cont'd)					
<u>7</u> /	Low-tempera- ture opera- tion:	T _C =-55° C-3° C					
3076	Forward-cur- ent transfer ratio:	I _C =-10Adc V _{CE} =-2Vdc		h _{FE}	23		
	Subgroup 4		λ=10				
1031	High-tempera- ture life (non-opera- ting):	$T_{\text{stg}} = +100^{\circ} + 3$ t = 1000 hrs. 8/	c	· 	gs 44 46		••
	End-Point tests	<u>:</u>					•
3036	Collector- base cutoff current:	Test Cond D		ICBO			mAdc
	2N1553A	V _{CB} =- 25Vdc			~~	-4.5	
	2N1554A	V _{CB} =-40Vdc				-4.5	
	2N1555A	V _{CB} =-55Vdc				-4.5 -4.5	
	2N1556A	$V_{CB}^{}$ 65Vde				-4.3)
3076	Forward-cur- rent transfer ratio:	I _C =-10Adc V _{CE} =-2Vdc		h _{FE}	23	70	
	Subgroup 5		λ=20				
1026	Steady-state operation life	$T_{C}^{=+80^{\circ}+3}C$ $P_{T}^{=20W}$ $V_{CB}^{=-15+10}V_{CB}$ $t=1000 \text{ hrs.}$	de				

End-Point tests:

Same as for Subgroup 4 above

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Table III. Group C inpsection. 1/- (Cont'd)

Test Method		<u>2</u> /	•	•	Limits	
per MIL-STD-750	Examination or test	Conditions	LTPD	Symbo1	Min Max	Unit

been reached at the temperature specified.

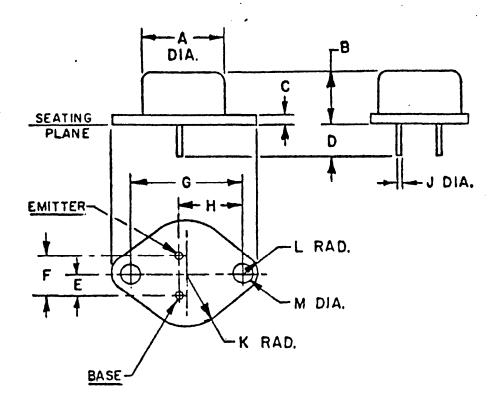
8/ See 4.2.3 herein.

^{1/} See 4.2.4 herein.
2/ See 4.2.2 herein.
3/ See 4.3.4 herein.
4/ Electrical rejects from the same lot under evaluation may be used for this test.

^{5/} See 4.3.5 herein.

6/ In this Subgroup, the sample units subjected to the HighTemperature Operation test shall be permitted to return to and be stabilized at room ambient temperature prior to their being subjected to the Low-Temperature Operation test.

7/ Measurement(s) shall be made after thermal equilibrium has

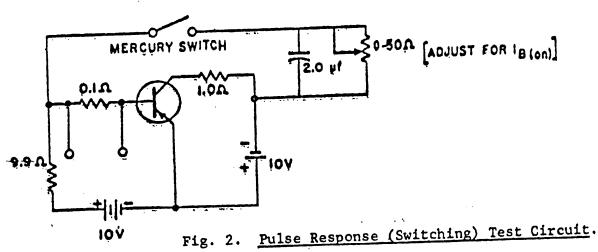


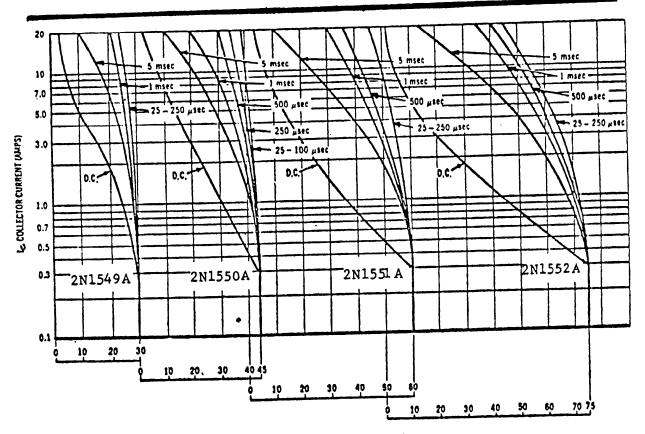
NOTES:

- 1. Metric equivalents (to the nearest .01 mm) are given for general information only and are based upon 1 inch = 25.4 mm.
- 2. This dimension should be measured at points .050 (1.27 mm) to .055 (1.40 mm) below seating plane. When gage is not used, measurement will be made at seating plane.
- 3. Two leads.
- 4. Collector shall be electrically connected to the case.

DIME NSIONS						
LTR	INCHES		MILLIM	HOLE		
LIR	MIN	MAX	MIN	MAX	E	
A		.875		22,23		
В	.250	.450	6.35	11.43	4	
С		.135		3.43		
D	.312	.500	7,92	12.70	3	
Ε	.205	.225	5.21	5.72		
F	.420	.410	10.67	11.18		
G	1.177	1.197	29.90	30.40		
Н	•655	.675	16.64	17.15	2	
7	.038	.052	.97	1.32	3	
K		.525		13.34		
L		.188		4.78		
М	.151	.161	3.84	4.09		

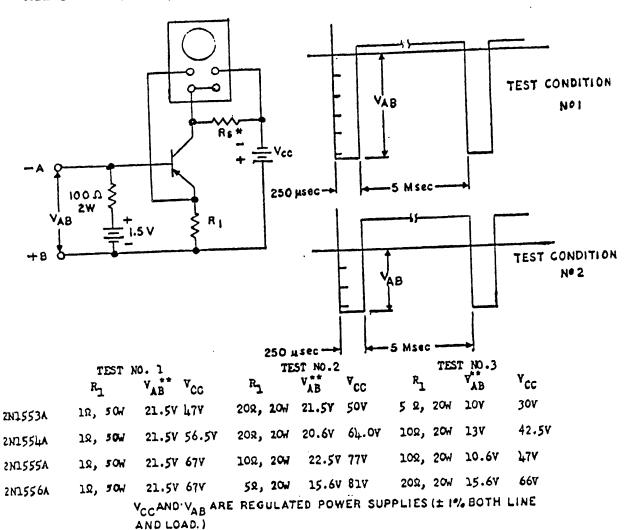
Figure 1. Outline and dimensions.





VCE COLLECTOR-EMITTER VOLTAGE (VOLTS)

Fig. 3. Safe Operating Area Curves.



- * RSIS O.IO NON INDUCTIVE 2 WATT. A CURRENT PROBE MAY BE USED IN LIEU OF THIS SENSE RESISTOR.
- ** ADJUSTMENT WILL BE NECESSARY TO SET THE EXACT CURRENT AND VOLTAGE POINTS SPECIFIED IN TEST 1,2 AND 3.

TEST Nº 3 A D.C. REGULATED SUPPLY IS CONNECTED TO POINTS A, B (MINUS TO POINT "A").

FIGURE 4. SAFE AREA TEST CIRCUIT

5. PREPARATION FOR DELIVERY

- 5.1 Preparation for delivery.-Preparation for delivery and the inspection of Preparation for Delivery shall be in accordance with Specification MIL-S-19500.
 - 6. NOTES
- 6.1 Notes.-The notes included in Specification MIL-S-19500, with the following additions or exceptions, are applicable to this specification.
- 6.2 "JAN"type transistors 2N1553A through 2N1556 are recommended as electrical and mechanical replacements for transistor types shown below:

MANY Marcon O	Replacement for		
JAN Type 2N1553A 2N1554A 2N1555A 2N1556A	2N1553, 2N677, CTP-1508 2N1554, 2N677A, CTP-1504 2N1555, CTP-1503 2N1556, 2N677B, 2N677C, CTP-1500		

- 6.3 Qualification.-With respect to products requiring qualification, awards will be made only for such products as have, prior to the time set for opening of bids, been tested and approved for inclusion in Qualified Products List (QPL)-19500, whether or not such products have actually been so listed by that date. Information pertaining to qualification of products covered by this specification should be requested from the Commanding General, U.S. Army Electronics Command, Fort Monmouth, New Jersey 07703, Attention: AMSEL-PP-EM-2.
- 6.4 Revision (document) changes.-Revision-letter symbols are not used in this revision to identify changes with respect to the previous issue, due to the extensiveness of the changes.

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